

2SC4418

Silicon NPN Triple Diffused Planar Transistor (High Voltage and High Speed Switching Transistor)

Application : Switching Regulator and General Purpose

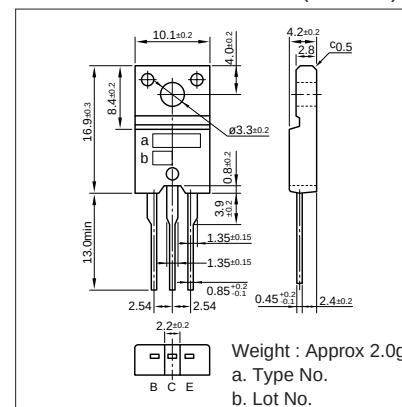
■ Absolute maximum ratings (Ta=25°C)

Symbol	2SC4418	Unit
V _{CB0}	500	V
V _{CE0}	400	V
V _{EB0}	10	V
I _c	5(Pulse10)	A
I _B	2	A
P _c	30(Tc=25°C)	W
T _j	150	°C
T _{stg}	-55 to +150	°C

■ Electrical Characteristics (Ta=25°C)

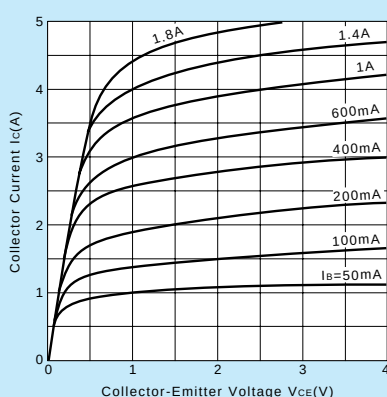
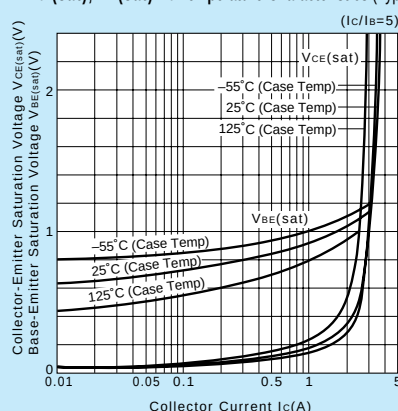
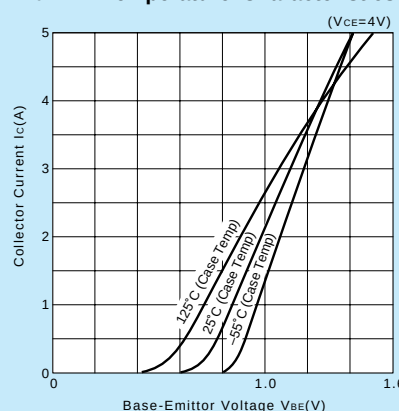
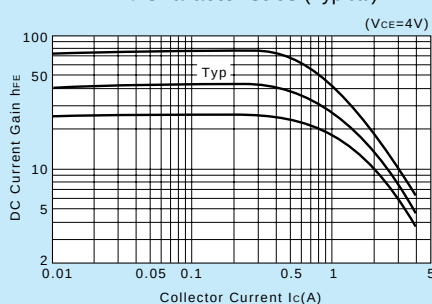
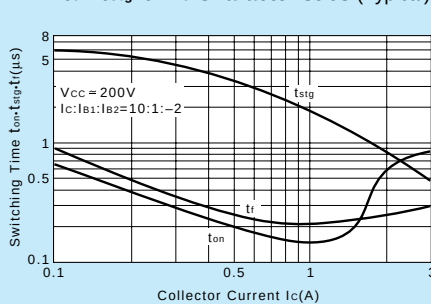
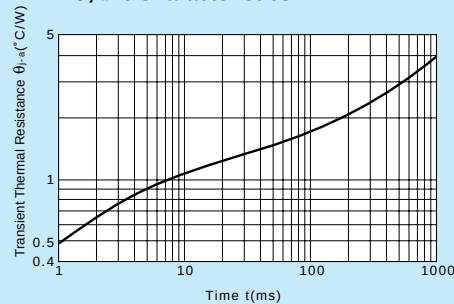
Symbol	Conditions	2SC4418	Unit
I _{CB0}	V _{CB} =500V	100max	μA
I _{EB0}	V _{EB} =10V	100max	μA
V _{(BR)CEO}	I _c =25mA	400min	V
h _{FE}	V _{CE} =4V, I _c =1.5A	10 to 30	
V _{CE(sat)}	I _c =1.5A, I _B =0.3A	0.5max	V
V _{BE(sat)}	I _c =1.5A, I _B =0.3A	1.3max	V
f _r	V _{CE} =12V, I _E =-0.3A	20typ	MHz
C _{OB}	V _{CB} =10V, f=1MHz	30typ	pF

External Dimensions FM20(TO220F)

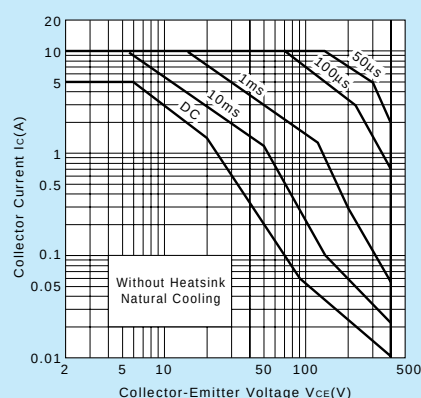


■ Typical Switching Characteristics (Common Emitter)

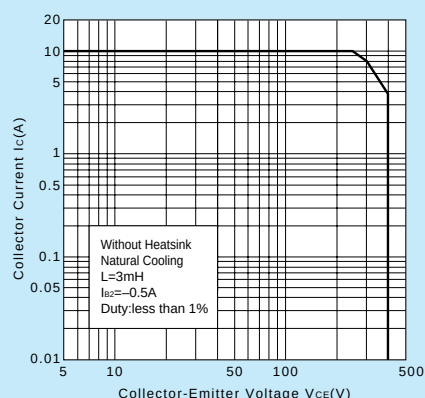
V _{CC} (V)	R _L (Ω)	I _c (A)	V _{BB1} (V)	V _{BB2} (V)	I _{B1} (A)	I _{B2} (A)	t _{on} (μs)	t _{stg} (μs)	t _f (μs)
200	133	1.5	10	-5	0.15	-0.3	1max	2.5max	0.5max

I_c-V_{CE} Characteristics (Typical)V_{CE(sat)}, V_{BE(sat)}-I_c Temperature Characteristics (Typical)I_c-V_{BE} Temperature Characteristics (Typical)h_{FE}-I_c Characteristics (Typical)t_{on}·t_{stg}·t_f-I_c Characteristics (Typical)θ_{j-a}-t Characteristics

Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area

P_c-T_a Derating